

Optimal representation of the polarization propagator for large-scale *GW* calculations

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Quasiparticle calculations based on the *GW* approximation are enhanced by introducing an optimal basis set for the polarization propagator, based on a Wannier representation of the one-electron wave functions, thus allowing the treatment of substantially larger systems. Our method is validated by calculating the vertical ionization energies of the benzene molecule and the band structure of bulk silicon. Its potentials are then demonstrated by addressing the quasiparticle spectrum of a model structure of vitreous silica, as well as of the tetraphenylporphyrin molecule.

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Density-functional theory (DFT) has grown into a powerful tool for the numerical simulation of matter at the nanoscale, allowing one to study the structure and dynamics of realistic models of materials consisting of up to a few thousand atoms these days.¹ The scope of standard DFT, however, is limited to those dynamical processes that do not involve electronic excitations. The most elementary such excitation is the removal/addition of an electron from a system originally in its ground state. These processes are accessible to direct/inverse photoemission spectroscopies and can be described in terms of *quasiparticle* (QP) spectra.² In insulators, the energy difference between the lowest-lying quasidelectron state and the highest-lying quasihole state is the QP band gap, a quantity that is severely (and to some extent erratically) underestimated by DFT (Ref. 3).

Many-body perturbation theory (MBPT), in turn, provides a general, though unwieldy, framework for QP and other excitation (such as optical) spectra.²⁻⁵ A numerically viable approach to QP energy levels (known as the *GW* approximation, GWA) was introduced in the 60s,⁶ but it took two decades for a realistic application of it to appear,⁷ and even today the numerical effort required by MBPT is such that its scope is limited to systems of a few handfuls of atoms. Even so, and in spite of the success met by MBPT in real materials,⁸ the approximations made for the most demanding of its applications are such as to shed some legitimate doubts on their general applicability. This situation will be referred to as the *size gap* of MBPT calculations.

In this Rapid Communication we present a strategy to substantially reduce the size gap of MBPT, based on the adoption of Wannier-type orbitals⁹⁻¹¹ to represent the response functions whose calculation is the main size-limiting factor of MBPT. Although we focus on QP spectra within the GWA, this strategy easily generalizes to optical spectra, as calculated from the Bethe-Salpeter equation.¹² Our method is benchmarked by the calculation of the ionization potential of the benzene molecule and of the band structure of bulk silicon and demonstrated by case calculations on vitreous silica and on the free-base tetraphenylporphyrin molecule (TPPH₂).

QP energies (QPE) are eigenvalues of a Schrödinger-type equation (QPEq) for the so-called QP amplitudes (QPA), which is similar to the DFT Kohn-Sham equation with the exchange-correlation potential, $V_{xc}(\mathbf{r})$, replaced by the non-

local, energy-dependent, and non-Hermitian self-energy operator, $\tilde{\Sigma}(\mathbf{r}, \mathbf{r}', E)$ (a tilde indicates the Fourier transform of a time-dependent function). Setting $\tilde{\Sigma}(\mathbf{r}, \mathbf{r}'; E) = -\frac{\rho(\mathbf{r}, \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}$ (ρ being the one-particle density matrix) would turn the QPEq into the Hartree-Fock equation. The next level of approximation is the GWA (Ref. 6) where $\tilde{\Sigma}$ is the product of the one-electron propagator, G , and of the dynamically screened interaction, W :

$$\tilde{\Sigma}_{GW}(\mathbf{r}, \mathbf{r}'; \tau) = iG(\mathbf{r}, \mathbf{r}'; \tau)W(\mathbf{r}, \mathbf{r}'; \tau), \quad (1)$$

where $\tau = t - t' > 0$, $W = v + v \cdot \Pi \cdot v$, $\Pi(\mathbf{r}, \mathbf{r}'; t - t') \doteq \frac{\delta n(\mathbf{r}, t)}{\delta v(\mathbf{r}', t')}$ is the reducible electron polarization propagator (polarizability), P its irreducible counterpart, $v(\mathbf{r}, \mathbf{r}'; t - t') = \frac{1}{|\mathbf{r} - \mathbf{r}'|} \delta(t - t')$ is the bare Coulomb interaction, n and V are the electron density distribution and external potential, respectively, and a dot indicates the product of two operators, such as in $v \cdot \Pi(\mathbf{r}, \mathbf{r}', t - t') = \int d\mathbf{r}'' dt'' v(\mathbf{r}, \mathbf{r}''; t - t'') \Pi(\mathbf{r}'', \mathbf{r}'; t'' - t')$.

The GWA alone does not permit to solve the QPEq, unless G and W are known, possibly depending on the solution of the QPEq itself. One of the most popular further approximations is the so-called G^0W^0 approximation (G^0W^0A), where the one-electron propagator is obtained from the QPEq using a model real and energy-independent self-energy, such as $\tilde{\Sigma}^0 = V_{xc}(\mathbf{r})\delta(\mathbf{r} - \mathbf{r}')$, and the irreducible polarizability is calculated in the random-phase approximation (RPA): $G^0(\mathbf{r}, \mathbf{r}'; \tau) = i \sum_v \psi_v(\mathbf{r}) \psi_v^*(\mathbf{r}') e^{-i\epsilon_v \tau} \theta(-\tau) - i \sum_c \psi_c(\mathbf{r}) \psi_c^*(\mathbf{r}') e^{-i\epsilon_c \tau} \theta(\tau)$ (ψ and ϵ are zeroth order QPAs and QPEs, referred to the Fermi energy, v and c suffixes indicate states below and above the Fermi energy, respectively, θ is the Heaviside step function), and $P^0(\mathbf{r}, \mathbf{r}'; \tau) = -iG^0(\mathbf{r}, \mathbf{r}'; \tau)G^0(\mathbf{r}', \mathbf{r}; -\tau)$. To first order in $\tilde{\Sigma}' = \tilde{\Sigma}_{G^0W^0} - \tilde{\Sigma}^0$, QPEs are given by the equation:

$$E_n \approx \epsilon_n + \langle \tilde{\Sigma}_{G^0W^0}^0(E_n) \rangle_n - \langle V_{XC} \rangle_n, \quad (2)$$

where $\langle A \rangle_n = \langle \psi_n | A | \psi_n \rangle$.

The apparently simple G^0W^0A still involves severe difficulties, mainly related to the calculation and manipulation of the polarizability that enters the definition of W^0 . These difficulties are often addressed using the so-called plasmon-pole approximation,⁷ which however introduces noticeable ambi-

guities and inaccuracies when applied to inhomogeneous systems.¹³ A well-established technique to address QP spectra in real materials without any crude approximations on response functions is the *space-time method* (STM) by Godby *et al.*¹⁴ In the STM the time/energy dependence of the $G^\circ W^\circ$ operators is represented on the imaginary axis, thus making them smooth (in the frequency domain) or exponentially decaying (in the time domain). The various operators are represented on a real-space grid, a choice which is straightforward, but impractical for systems larger than a few handfuls of inequivalent atoms. In this Rapid Communication we combine the imaginary time/frequency approach of the STM with a representation of the response functions, based on localized Wannier-type orbitals, thus enhancing the scope of MBPT calculations so as to embrace systems potentially as large as a few hundred atoms.

In the STM, the self-energy expectation value in Eq. (2) is obtained by analytically continuing to the real frequency axis the Fourier transform of the expression

$$\langle \Sigma_{G^\circ W^\circ}(i\tau) \rangle_n = \mp \sum_l e^{\epsilon_l \tau} \times \int \psi_n(\mathbf{r}) \psi_l(\mathbf{r}) \psi_l(\mathbf{r}') \psi_n(\mathbf{r}') \times W(\mathbf{r}, \mathbf{r}'; i\tau) d\mathbf{r} d\mathbf{r}', \quad (3)$$

where the upper (lower) sign holds for positive (negative) times, the sum extends below (above) the Fermi energy, and QPAs are assumed to be real, because of time-reversal invariance. By substituting v for W , Eq. (3) yields the exchange self-energy, whereas $v \cdot \Pi \cdot v$ yields the correlation contribution, Σ_C , whose evaluation is the main size-limiting step of GW calculations.

Suppose that a small, time-independent, basis set to represent the polarizability can be found: $\Pi(\mathbf{r}, \mathbf{r}', i\tau) \approx \sum_{\mu\nu} \Pi_{\mu\nu}(i\tau) \bar{\Phi}_\mu(\mathbf{r}) \bar{\Phi}_\nu(\mathbf{r}')$. Equation (3) then gives

$$\langle \Sigma_C(i\tau) \rangle_n \approx \mp \sum_{l\mu\nu} e^{\epsilon_l \tau} \Pi_{\mu\nu}(i\tau) S_{nl,\mu} S_{nl,\nu} \theta(E_C^1 - \epsilon_l), \quad (4)$$

where $S_{nl,\nu} = \int \psi_n(\mathbf{r}) \psi_l(\mathbf{r}) \frac{1}{|\mathbf{r}-\mathbf{r}'|} \bar{\Phi}_\nu(\mathbf{r}') d\mathbf{r} d\mathbf{r}'$ and E_C^1 is an energy cutoff that limits the number of conduction states to be used in the calculation of the self-energy. The existence of such a basis for the representation of static dielectric matrices has been demonstrated in Ref. 15. A convenient representation of the polarizability would thus allow QPEs to be calculated from Eq. (2), by analytically continuing to the real axis the Fourier transform of Eq. (4). Such an optimal representation is identified in two steps: (i) we first express the Kohn-Sham orbitals, whose products enter the definition of P° , in terms of localized, Wannier-type, orbitals; (ii) we then construct a basis set of localized functions for the manifold spanned by products of Wannier orbitals, such that their norm is larger than a given threshold.

Let us start from the RPA irreducible polarizability:

$$\tilde{P}^\circ(\mathbf{r}, \mathbf{r}'; i\omega) = \sum_{cv} \Phi_{cv}(\mathbf{r}) \Phi_{cv}(\mathbf{r}') \tilde{\chi}_{cv}^\circ(i\omega), \quad (5)$$

where $\tilde{\chi}_{cv}^\circ(i\omega) = 2 \operatorname{Re}(\frac{1}{i\omega - \epsilon_c + \epsilon_v})$ and $\Phi_{cv}(\mathbf{r}) = \psi_c(\mathbf{r}) \psi_v(\mathbf{r})$. We express valence and conduction QPAs in terms of localized, Wannier-type, orbitals:

$$u_s(\mathbf{r}) = \sum_v \mathcal{U}_{sv}^{-1} \psi_v(\mathbf{r}) \theta(-\epsilon_v),$$

$$v_s(\mathbf{r}) = \sum_c \mathcal{V}_{sc}^{-1} \psi_c(\mathbf{r}) \theta(\epsilon_c) \theta(E_C^2 - \epsilon_c), \quad (6)$$

where $E_C^2 \leq E_C^1$ is a second energy cutoff that limits a *lower conduction manifold* (LCM) to be used in the construction of the polarization basis. According to the choice of the \mathcal{U} and \mathcal{V} matrices, the u 's and v 's can be either maximally localized^{9,11} or nonorthogonal generalized¹⁶ Wannier functions. We then reduce the number of product functions necessary to represent the Φ 's from the product between the number of valence and conduction states, which scales quadratically with the system size, to a number that scales linearly. To this end, we express the Φ 's as approximate linear combinations of products of the u 's v 's: $\Phi_{cv}(\mathbf{r}) \approx \sum_{rs} \mathcal{O}_{cv,rs} \mathcal{W}_{rs}(\mathbf{r}) \theta(|\mathcal{W}_{rs}|^2 - s_1)$, where $\mathcal{O}_{cv,c'v'} = \mathcal{U}_{vv'} \mathcal{V}_{cc'}$, $\mathcal{W}_{rs}(\mathbf{r}) = u_r(\mathbf{r}) v_s(\mathbf{r})$, $|\mathcal{W}_{rs}|$ is the L^2 norm of $\mathcal{W}_{rs}(\mathbf{r})$, which is arbitrarily small when the centers of the u_r and v_s functions are sufficiently distant, and s_1 is an appropriate cutoff. The number of products can be further reduced on account of the nonorthogonality and mutual linear dependence of the \mathcal{W} 's. To this end, let us define the overlap matrix: $\mathcal{Q}_{\rho\sigma} = \int \mathcal{W}_\rho(\mathbf{r}) \mathcal{W}_\sigma(\mathbf{r}) d\mathbf{r}$, where the ρ and σ indices stand for pairs of rs indices. The magnitude of the eigenvalues is a measure of linear dependence, and an orthonormal basis can be obtained by retaining only those eigenvectors \mathcal{U}_v whose eigenvalue, q_v , is larger than a given threshold, s_2 : $\bar{\Phi}_v(\mathbf{r}) \approx \frac{1}{\sqrt{q_v}} \sum_\rho \mathcal{U}_{v\rho} \mathcal{W}_\rho(\mathbf{r})$, for $q_v > s_2$. It can be demonstrated that the manifold thus generated coincides with that spanned by the eigenvectors of the polarizability, calculated at zero time, corresponding to eigenvalues larger than the same threshold.¹⁷

Once an optimal basis set has been thus identified, an explicit representation for the irreducible polarizability,

$$\tilde{P}^\circ(\mathbf{r}, \mathbf{r}', i\omega) = \sum_{\mu\nu} \tilde{P}_{\mu\nu}^\circ(i\omega) \bar{\Phi}_\mu(\mathbf{r}) \bar{\Phi}_\nu(\mathbf{r}'), \quad (7)$$

is obtained. By equating Eq. (5) to Eq. (7) and taking into account the orthonormality of the $\bar{\Phi}$'s, one obtains

$$\tilde{P}_{\nu\mu}^\circ(i\omega) = \sum_{cv} T_{cv,\mu} T_{cv,\nu} \tilde{\chi}_{cv}^\circ(i\omega) \theta(E_C^1 - \epsilon_c), \quad (8)$$

where $T_{cv,\mu} = \int \Phi_{cv}(\mathbf{r}) \bar{\Phi}_\mu(\mathbf{r}) d\mathbf{r}$. A representation for Π is finally obtained by simple matrix manipulations.

Our scheme has been implemented in the QUANTUM ESPRESSO density-functional package,¹⁸ for norm-conserving (NC) as well as ultrasoft (US) pseudopotentials (PPs), resulting in a new module called `gww.x` which uses a Gauss-Legendre discretization of the imaginary time/frequencies half-axes, and that is parallelized accordingly. We first illustrate our scheme by considering an isolated benzene molecule in a periodically repeated cubic cell with an edge of 20 a.u. using a first conduction energy cutoff $E_C^1 = 56.7$ eV, corresponding to 1000 conduction states, and a cutoff on the norm of Wannier products $s_1 = 0.1$ a.u. (Ref. 19). In Fig. 1 we display the dependence of the calculated ionization po-

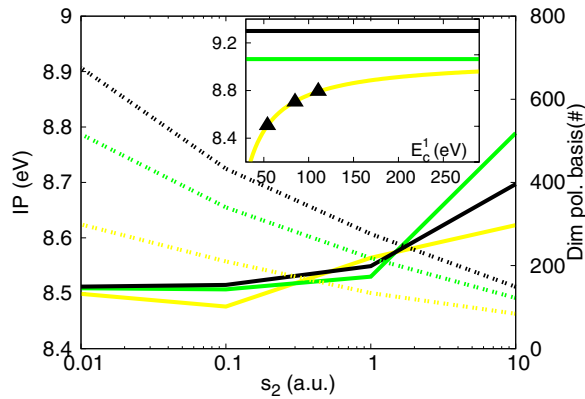


FIG. 1. (Color online) Calculated ionization potential of the benzene molecule (solid lines, left scale) and dimension of the polarization basis (dashed lines, right scale) versus the s_2 cutoff. The polarization basis has been constructed with a conduction energy cutoff $E_C^2=16.7$ eV [light-gray (yellow), 100 states], $E_C^2=28.6$ eV [gray (green), 300 states], and $E_C^2=38.3$ eV [black, 500 states]. Inset: calculated ionization potential as a function of the overall conduction energy cutoff, E_C^1 . Black line: experimental value; light-gray (yellow) line: fit to the calculated values [black triangles]; gray (green) line extrapolated value. See text for more details.

tential (IP) on the second conduction energy cutoff used to define the polarization basis, E_C^2 , and on the cutoff on the eigenvalues of the overlap matrix between Wannier products, s_2 . Convergence within 0.01 eV is achieved with a conduction energy cutoff E_C^2 of 29 eV (300 states) and a polarization basis set of only ~ 400 elements. The convergence of other QPEs is similar. The inset of Fig. 1 shows the convergence of the IP with respect to E_C^1 , which turns out to be unexpectedly slow. These data can be accurately fitted by the simple formula $\text{IP}(E_C^1)=\text{IP}(\infty)+A/E_C^1$, resulting in a predicted ionization potential $\text{IP}(\infty)=9.1$ eV, in good agreement with the experimental value of 9.3 eV.²⁰ The potential of our method for large molecular system is illustrated by a calculation for the TPPH₂ molecule (C₄₄H₃₀N₄) in a periodically repeated orthorhombic supercell of $37.8 \times 37.8 \times 26.5$ a.u..¹⁹ Using values of 31.1, 40.5, and 48.1 eV for E_C^1 (corresponding to 2000, 3000, and 4000 conduction states) and $E_C^2=17.2$ eV (corresponding to 750 conduction states), $s_1=1.5$ and $s_2=0.01$ a.u., which lead to a basis of 2797 elements, yields an extrapolated $\text{IP}(\infty)$ of 6.0 eV, in fair agreement with the experimental value of 6.4 eV.²¹

In order to demonstrate our scheme for extended systems,²² we consider bulk silicon treated using a 64-atom cubic cell¹⁹ at the experimental lattice constant and sampling the corresponding Brillouin zone (BZ) using the Γ point only. This gives the same sampling of the electronic states as would result from six points in the irreducible wedge of the BZ of the elementary two-atom unit cell. Our calculations were performed using $E_C^1=94.6$ eV (corresponding to 3200 conduction states) and $E_C^2=33.8$ eV (corresponding to 800 states in the LCM), $s_1=1.0$ a.u. and two distinct values for s_2 (0.01 and 0.001). In Table I we summarize our results and compare them with previous theoretical results, as well as with experiments. An overall convergence within a few tens meV is achieved with a s_2 cutoff of 0.001 a.u., corresponding

TABLE I. QPEs (eV) calculated in bulk silicon and compared with experimental (as quoted in Ref. 14) and previous theoretical results (Ref. 14). “Th₁” and “Th₂” indicate calculations made with $s_2=0.01$ and $s_2=0.001$ a.u., respectively, while N_p is the dimension of the polarization basis.

	Th ₁	Th ₂	Previous theor	Expt.
N_p	4847	6510		
Γ_{1v}	-11.45	-11.49	-11.57	-12.5 ± 0.6
X_{1v}	-7.56	-7.58	-7.67	
X_{4v}	-2.79	-2.80	-2.80	$-2.9, -3.3 \pm 0.2$
Γ'_{25c}	0.	0.	0.	0.
X_{1c}	1.39	1.41	1.34	1.25
Γ'_{15c}	3.22	3.24	3.24	3.40, 3.05
Γ'_{2c}	3.87	3.89	3.94	4.23, 4.1

to a polarization basis of ~ 6500 elements. The residual small discrepancy with respect to previous results¹⁴ is likely due to our use of a 64-atom supercell, rather than the more accurate k -point sampling used in previous work. Our ability to treat large supercells gives us the possibility to deal with disordered systems that could hardly be addressed using conventional approaches. In Fig. 2 we show the QPE density of states as calculated for a 72-atom model of vitreous silica.^{19,23} We used $E_C^1=48.8$ eV (corresponding to 1000 conduction states), $E_C^2=30.2$ eV (corresponding to 500 states in the LCM), $s_1=1$ a.u. and $s_2=0.1$ a.u. (giving rise to a polarization basis of 3152 elements). We checked the convergence respect to the polarization basis by considering $s_2=0.01$ a.u. which leads to a basis of 3933 elements. Indeed, the calculated QPEs differ in average only 0.01 eV with a maximum discrepancy of 0.07 eV.²⁴ The quasiparticle band gap resulting from our calculations is 8.5 eV, to be compared with an experimental value of ~ 9 eV (Ref. 25) and with a significantly lower value given by DFT in the local-density approximation (5.6 eV).

For estimating the reduction of the polarization basis size that can be achieved with our method, we start from the least favorable case, i.e., when the localization of Wannier functions is relatively poor, as in bulk Si. In Ref. 14, where a plane-waves (PWs) basis was used, the number of PWs yielding an accuracy of 0.05 eV was on the order of 400 for

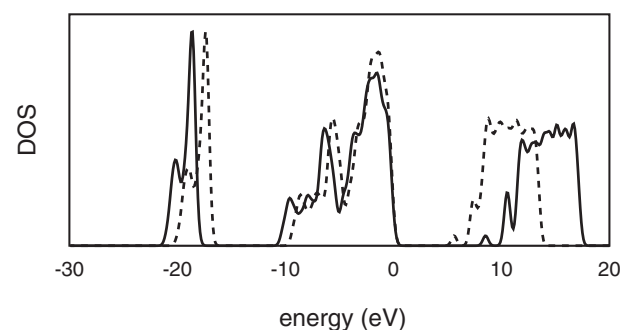


FIG. 2. Electronic density of states for a model of vitreous silica: LDA (dashed line) and GW (solid line). A Gaussian broadening of 0.25 eV has been used.

a two-atom unit cell. A same accuracy was achieved by the present method using a basis of ~ 6500 elements for a 64-atom cell, corresponding to ~ 200 elements in the two-atom cell. We note that an equivalent PWs basis would require for the TPPH₂ system $\sim 28\,000$ elements while only 2787 are required by our scheme.

In conclusion, we believe that expressing density response functions in terms of optimal basis sets will permit to enhance the scope of many-body perturbation theory to large models of molecular and extended, possibly disordered, sys-

tems. The extension of the methodology presented in this Rapid Communication for quasiparticle spectra to optical spectroscopies using the Bethe-Salpeter formalism is straightforward and presently under way.

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